REVISIONS			
LTR	**DESCRIPTION**	**DATE**	**APPROVED**
A	Make changes to t_{ON}, t_{OFF}, Break before make time delay, and Charge injection test limits as specified under Dual and Single sections of Table I. Update document paragraphs to current requirements. - ro	21-08-12	J. ESCHMEYER

Prepared in accordance with ASME Y14.24

Vendor item drawing

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REV STATUS OF PAGES	**REV**		A	A	A	A	A	A	A	A	A	A	A	A								
	PAGE		1	2	3	4	5	6	7	8	9	10	11	12								

PMIC N/A	**PREPARED BY** Phu H. Nguyen	**DLA LAND AND MARITIME** **COLUMBUS, OHIO 43218-3990** **https://www.dla.mil/LandandMaritime**
Original date of drawing YY-MM-DD 11-01-19	**CHECKED BY** Phu H. Nguyen **APPROVED BY** Thomas M. Hess	TITLE MICROCIRCUIT, DIGITAL, CMOS, ±5 V / +5V, 4 Ω, SINGLE SPDT SWITCH, MONOLITHIC SILICON
	SIZE **A** / **CODE IDENT. NO.** **16236**	**DWG NO.** **V62/11608**
	REV **A**	**PAGE** 1 **OF** 12

DISTRIBUTION STATEMENT A. Approved for public release. Distribution is unlimited.

AMSC N/A

5962-V057-21

1. SCOPE

1.1 Scope. This drawing documents the general requirements of a high performance CMOS, ±5 V/ +5 V, 4 Ω, single, single pole double throw (SPDT) switch microcircuit, with an operating temperature range of -55°C to +125°C.

1.2 Vendor Item Drawing Administrative Control Number. The manufacturer's PIN is the item of identification. The vendor item drawing establishes an administrative control number for identifying the item on the engineering documentation:

V62/11608	-	01	X	E
Drawing number		Device type (See 1.2.1)	Case outline (See 1.2.2)	Lead finish (See 1.2.3)

1.2.1 Device type(s).

Device type	Generic	Circuit function
01	ADG619-EP	CMOS, ±5 V/ +5 V, 4 Ω, single SPDT switch

1.2.2 Case outline(s). The case outline(s) are as specified herein.

Outline letter	Number of pins	JEDEC PUB 95	Package style
X	8	JEDEC MO-178	Small outline Package

1.2.3 Lead finishes. The lead finishes are as specified below or other lead finishes as provided by the device manufacturer:

Finish designator	Material
A	Hot solder dip
B	Tin-lead plate
C	Gold plate
D	Palladium
E	Gold flash palladium
F	Tin-lead alloy (BGA/CGA)
Z	Other

1.3 Absolute maximum ratings. 1/

Voltage referenced :

V_{DD} to V_{SS}	13.0 V
V_{DD} to GND	-0.3 V to +6.5 V
V_{SS} to GND	+0.3 V to -6.5 V
Analog input 2/	V_{SS} – 0.3 V to V_{DD} + 0.3 V
Digital input 2/	-0.3 V to V_{DD} + 0.3 V or 30 mA (whichever occurs first)
Peak current, S or D	100 mA (pulsed at 1 ms, 10% duty cycle maximum)
Continuous current, S or D	50 mA
Ambient operating temperature range	-55°C to +125°C
Storage temperature range	-65°C to +150°C
Maximum junction temperature (T_J)	150°C
Thermal impedance:	
Junction to ambient (θ_{JA})	229°C /W
Junction to case (θ_{JC})	91.99°C /W
Lead soldering:	
Reflow, peak temperature	260(+0/-5)°C
Time at peak temperature	20 seconds to 40 seconds

1/ Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

2/ Overvoltage at IN, S or D are clamped by internal diodes. Current should be limited to the maximum ratings given.

2. APPLICABLE DOCUMENTS

JEDEC Solid State Technology Association

JEDEC PUB 95 – Registered and Standard Outlines for Semiconductor Devices

(Copies of these documents are available online at https://www.jedec.org.)

3. REQUIREMENTS

3.1 Marking. Parts shall be permanently and legibly marked with the manufacturer's part number as shown in 6.3 herein and as follows:

A. Manufacturer's name, CAGE code, or logo
B. Pin 1 identifier
C. ESDS identification (optional)

3.2 Unit container. The unit container shall be marked with the manufacturer's part number and with items A and C (if applicable) above.

3.3 Electrical characteristics. The maximum and recommended operating conditions and electrical performance characteristics are as specified in 1.3, 1.4, and table I herein.

3.4 Design, construction, and physical dimension. The design, construction, and physical dimensions are as specified herein.

3.5 Diagrams.

3.5.1 Case outline. The case outline shall be as shown in 1.2.2 and figure 1.

3.5.2 Terminal connections. The terminal connections shall be as shown in figure 2.

3.5.3 Functional block diagram. The functional block diagram shall be as shown in figure 3.

3.5.4 Truth table. The truth table shall be as shown in figure 4.

3.5.5 On Resistance. The On resistance shall be as shown in figure 5.

3.5.6 Off Leakage. The Off leakage shall be as shown in figure 6.

3.5.7 On leakage. The On leakage shall be as shown in figure 7.

3.5.8 Switching times. The switching times shall be as shown in figure 8.

3.5.9 Break before making time delay. The break before making time delay shall be as shown in figure 9.

3.5.10 Charge injection. The charge injection shall be as shown in figure 10.

3.5.11 Off isolation. The Off isolation shall be as shown in figure 11.

3.5.12 Channel to channel crosstalk. The channel to channel crosstalk shall be as shown in figure 12.

3.5.13 Bandwidth. The bandwidth shall be as shown in figure 13.

TABLE I. Electrical performance characteristics. 1/

Test	Symbol	Test conditions V_{DD} = 5 V ±10%, V_{SS} = -5 V ±10%, GND = 0 V unless otherwise specified	Limits				Unit
			T_A = 25°C		-55°C ≤ T_A ≤ +125°C		
			Min	Max	Min	Max	
DUAL SUPPLY							
Analog switch							
Analog signal range		V_{DD} = +4.5 V, V_{SS} = -4.5 V			V_{SS}	V_{DD}	V
On resistance	R_{ON}	V_S = ±4.5 V, I_{DS} = -10 mA, see figure 5		6.5		10	Ω
R_{ON} Match between channels	ΔR_{ON}	V_S = ±4.5 V, I_{DS} = -10 mA		1.1		1.45	Ω
On resistance flatness	$R_{FLAT (ON))}$	V_S = ±3.3 V, I_{DS} = -10 mA		1.35		1.6	Ω
Leakage currents (V_{DD} = +5.5 V, V_{SS} = -5.5 V)							
Source off leakage,	$I_{S(Off)}$	V_S = ±4.5 V, V_D = ±4.5 V, see figure 6		±0.25		±3	nA
Channel On leakage,	I_D, I_S (On)	V_S = V_D = ±4.5 V, see figure 7		±0.25		±25	nA
Digital inputs							
Input high voltage	V_{INH}				2.4		V
Input low voltage	V_{INL}					0.8	V
Input current,	I_{NL} or I_{NH}	V_{IN} = V_{INL} or V_{INH}	0.005 TYP			±0.1	µA
Digital input capacitance	C_{IN}		2 TYP				pF
Dynamic characteristic 2/							
t_{ON}		R_L = 300 Ω, C_L = 35 pF, V_S = 3.3 V, see figure 8		120		215	ns
t_{OFF}				75		105	ns
Break before make time delay	t_{BBM}	R_L = 300 Ω, C_L = 35 pF, V_{S1} = V_{S2} = 3.3 V, see figure 9	40 TYP		10		ns
Charge injection		V_S = 0 V, R_S = 0 Ω, C_L = 1 nF, see figure 10	110 TYP				pC
Off isolation		R_L = 50 Ω, C_L = 5 pF, f = 1 MHz, see figure 11	- 67 TYP				dB
Channel to channel crosstalk		R_L = 50 Ω, C_L = 5 pF, f = 1 MHz, see figure 12	- 67 TYP				dB
Bandwidth -3 dB		R_L = 50 Ω, C_L = 5 pF, see figure 13	190 TYP				MHz
C_S (Off)		f = 1 MHz	25 TYP				pF
C_D, C_S (On)			95 TYP				pF
Power requirements (V_{DD} = +5.5 V, V_{SS} = -5.5 V)							
I_{DD}		Digital inputs = 0 V or 5.5 V	0.001 TYP			1.0	µA
I_{SS}			0.001 TYP			1.0	µA

See footnotes at end of table.

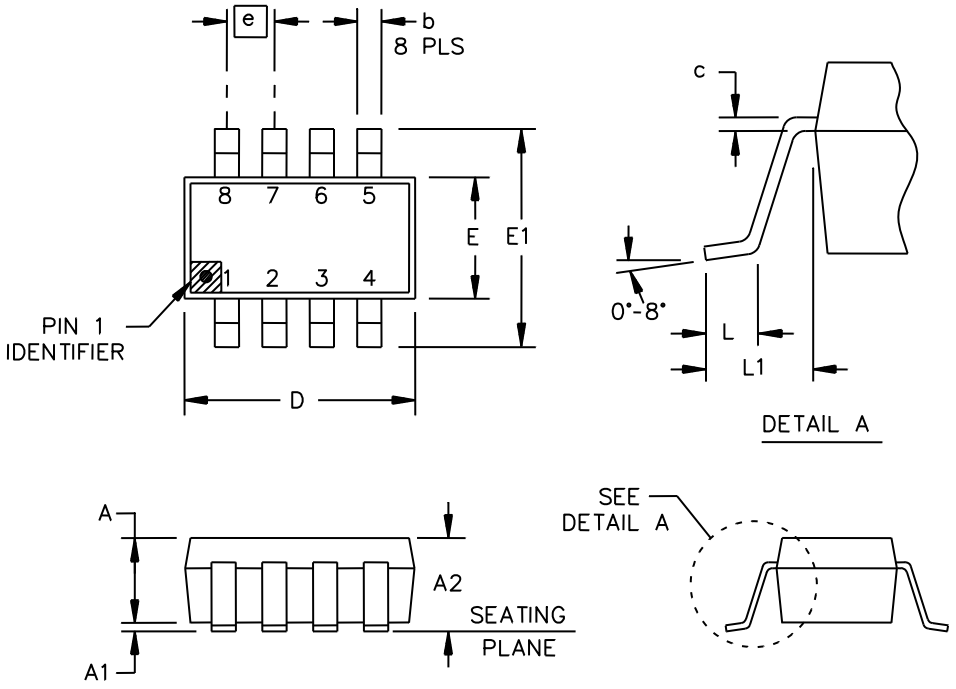
TABLE I. Electrical performance characteristics Continued. 1/

Test	Symbol	Test conditions V_{DD} = 5 V ±10%, V_{SS} = 0 V, GND = 0 V unless otherwise specified	Limits				Unit
			T_A = 25°C		-55°C ≤ T_A ≤ +125°C		
			Min	Max	Min	Max	
SINGLE SUPPLY							
Analog switch							
Analog signal range		V_{DD} = +4.5 V, V_{SS} = 0 V			0	V_{DD}	V
On resistance	R_{ON}	V_S = 0 V to 4.5 V, I_{DS} = -10 mA, see figure 5		10		14	Ω
R_{ON} Match between channels	ΔR_{ON}	V_S = 0 V to 4.5 V, I_{DS} = -10 mA		1.1		1.4	Ω
On resistance flatness	$R_{FLAT (ON))}$	V_S =1.5 V to 3.3 V, I_{DS} = -10 mA	0.5 TYP			1.4	Ω
Leakage currents (V_{DD} = +5.5 V)							
Source off leakage,	I_S(Off)	V_S = 1 V/4.5 V, V_D = 4.5 V/1 V, see figure 6		±0.25		±3	nA
Channel On leakage,	I_D, I_S (On)	V_S = V_D = ±4.5 V, see figure 7		±0.25		±25	nA
Digital inputs							
Input high voltage	V_{INH}				2.4		V
Input low voltage	V_{INL}					0.8	V
Input current,	I_{NL} or I_{NH}	V_{IN} = V_{INL} or V_{INH}	0.05 TYP			±0.1	µA
Digital input capacitance	C_{IN}		2 TYP				pF
Dynamic characteristic 2/							
t_{ON}		R_L = 300 Ω, C_L = 35 pF, V_S = 3.3 V, see figure 8		220		390	ns
t_{OFF}				75		135	ns
Break before make time delay	t_{BBM}	R_L = 300 Ω, C_L = 35 pF, V_{S1} = V_{S2} = 3.3 V, see figure 9	70 TYP		10		ns
Charge injection		V_S -= 0 V, R_S = 0 Ω, C_L = 1 nF, see figure 10	6 TYP				pC
Off isolation		R_L = 50 Ω, C_L = 5 pF, f = 1 MHz, see figure 11	- 67 TYP				dB
Channel to channel crosstalk		R_L = 50 Ω, C_L = 5 pF, f = 1 MHz, see figure 12	- 67 TYP				dB
Bandwidth -3 dB		R_L = 50 Ω, C_L = 5 pF, see figure 13	190 TYP				MHz
C_S (Off)		f = 1 MHz	25 TYP				pF
C_D, C_S (On)		f = 1 MHz	95 TYP				pF
Power requirements (V_{DD} = +5.5 V)							
I_{DD}		Digital inputs = 0 V or 5.5 V	0.001 TYP			1.0	µA

1/ Testing and other quality control techniques are used to the extent deemed necessary to assure product performance over the specified temperature range. Product may not necessarily be tested across the full temperature range and all parameters may not necessarily be tested. In the absence of specific parametric testing, product performance is assured by characterization and/or design.

2/ Guaranteed by design, not subject to production test.

Case X



Dimensions					
Symbol	Millimeters		Symbol	Millimeters	
	Min	Max		Min	Max
A	0.90	1.30	E	1.50	1.70
A1	0.05	0.15	E1	2.60	3.00
A2	0.95	1.45	e	0.65 BSC	
b	0.22	0.38	L	0.30	0.60
c	0.08	0.22	L1	0.60 BSC	
D	2.80	3.00			

FIGURE 1. Case outline.

Case outline X

Terminal number	Terminal symbol	Description
1	D	Drain terminal. Can be an input or output.
2	S1	Source terminal. Can be an input or output.
3	GND	Ground (0 V) reference.
4	V_{DD}	Most positive power supply.
5	NC	No connect. Not internally connected.
6	IN	Logic control input.
7	V_{SS}	Most negative power supply. This pin is only used in dual supply applications and should be tied to ground in single supply applications.
8	S2	Source terminal. Can be an input or output.

FIGURE 2. Terminal connections.

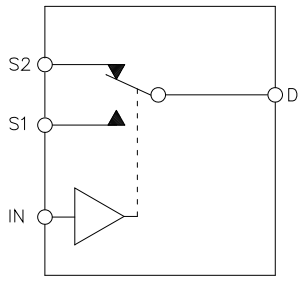


FIGURE 3. Functional block diagram.

IN	Switch S1	Switch S2
0	On	Off
1	Off	On

FIGURE 4. Truth table.

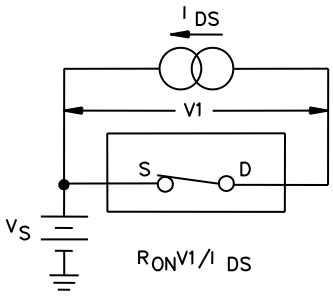


FIGURE 5. ON Resistance.

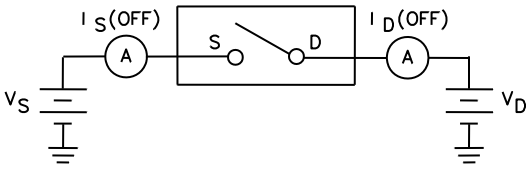


FIGURE 6. OFF leakage.

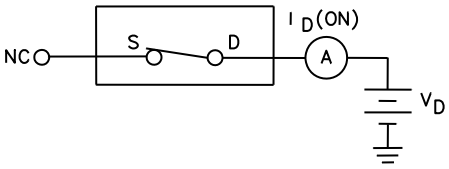


FIGURE 7. ON Leakage.

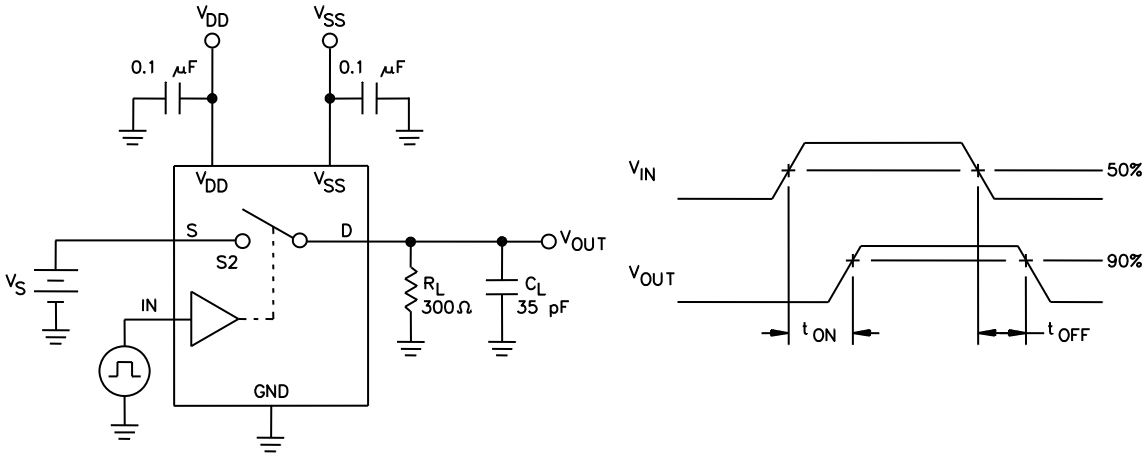


FIGURE 8. Switching times.

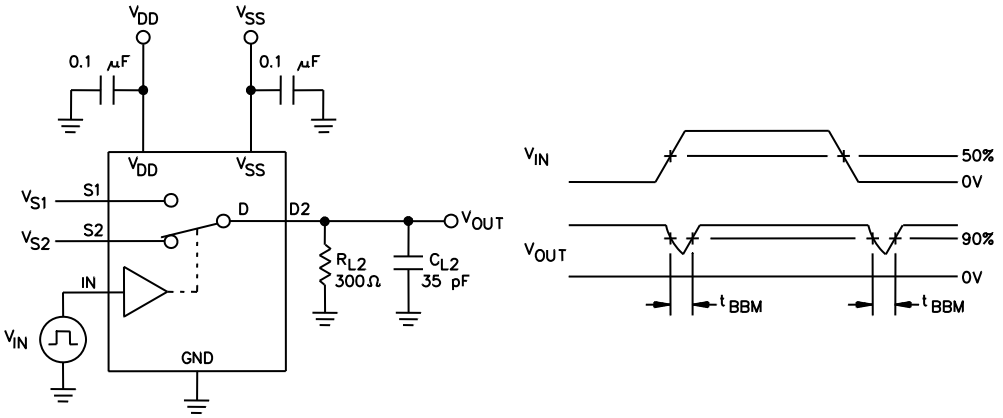


FIGURE 9. Break before make time delay.

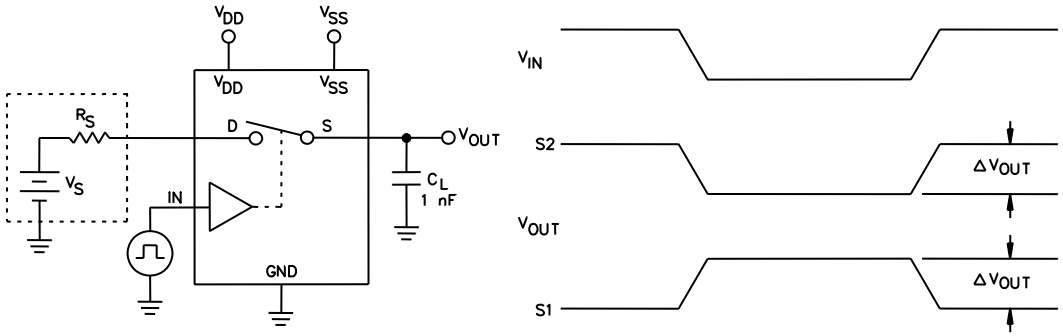
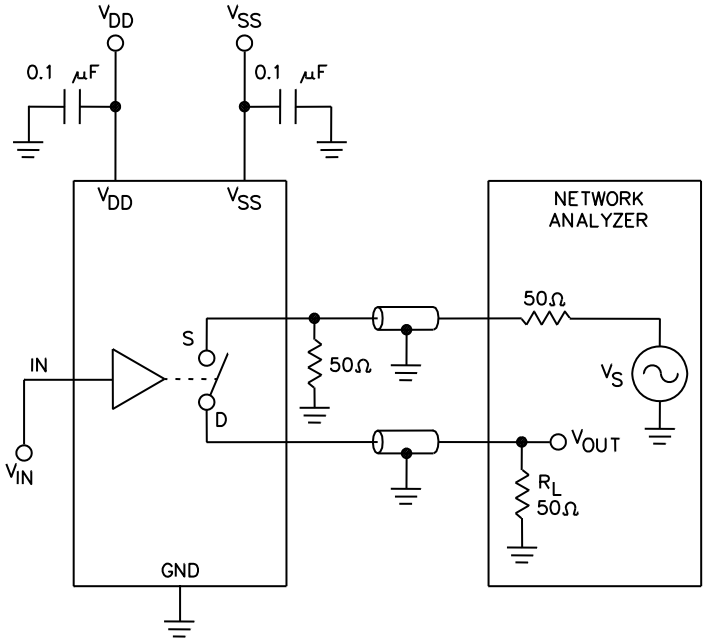
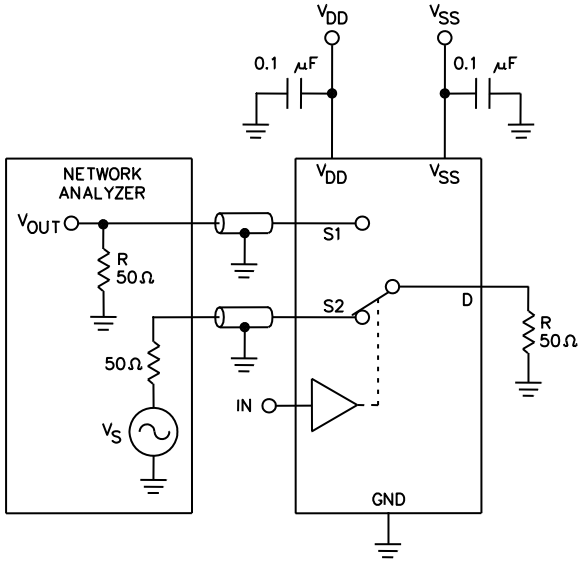


FIGURE 10. Charge injection.



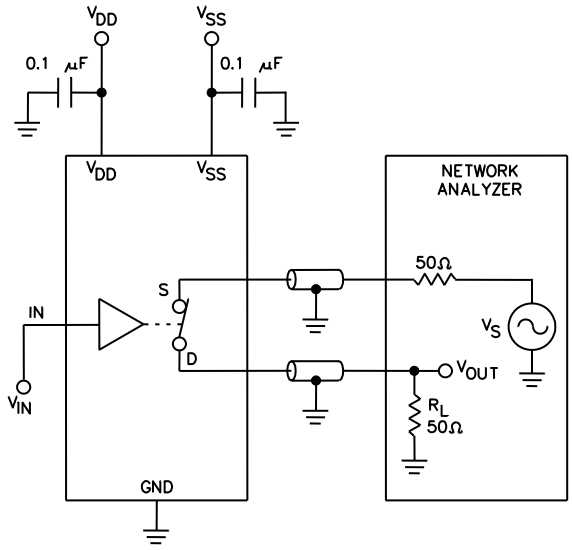
$$\text{OFF ISOLATION} = 20 \log \frac{V_{OUT}}{V_S}$$

FIGURE 11. Off isolation.



$$\text{CHANNEL-TO-CHANNEL CROSSTALK} = 20 \log \frac{V_{OUT}}{V_S}$$

FIGURE 12. Channel to channel crosstalk.



$$\text{INSERTION LOSS} = 20 \log \frac{V_{OUT} \text{ WITH SWITCH}}{V_S \text{ WITHOUT SWITCH}}$$

FIGURE 13. Bandwidth.

4. VERIFICATION

4.1 Product assurance requirements. The manufacturer is responsible for performing all inspection and test requirements as indicated in their internal documentation. Such procedures should include proper handling of electrostatic sensitive devices, classification, packaging, and labeling of moisture sensitive devices, as applicable.

5. PREPARATION FOR DELIVERY

5.1 Packaging. Preservation, packaging, labeling, and marking shall be in accordance with the manufacturer's standard commercial practices for electrostatic discharge sensitive devices.

6. NOTES

6.1 ESDS. Devices are electrostatic discharge sensitive and are classified as ESDS class 1 minimum.

6.2 Configuration control. The data contained herein is based on the salient characteristics of the device manufacturer's data book. The device manufacturer reserves the right to make changes without notice. This drawing will be modified as changes are provided.

6.3 Suggested source(s) of supply. Identification of the suggested source(s) of supply herein is not to be construed as a guarantee of present or continued availability as a source of supply for the item. DLA Land and Maritime maintains an online database of all current sources of supply at https://landandmaritimeapps.dla.mil/programs/smcr/.

Vendor item drawing administrative control number 1/	Device manufacturer CAGE code	Vendor part number
V62/11608-01XE	24355	ADG619SRJZ-EP-RL7

1/ The vendor item drawing establishes an administrative control number for identifying the item on the engineering documentation.

CAGE code	Source of supply
24355	Analog Devices Rt 1 Industrial Park PO Box 9106 Norwood, MA 02062 Point of contact: 20 Alpha Road Chelmsford, MA 01824-4123

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Analog Devices Inc.:

ADG619BRMZ-REEL7 ADG619BRTZ-REEL7 ADG619BRTZ-REEL ADG619BRMZ ADG619BRMZ-REEL ADG619SRJZ-EP-RL7 ADG619BRTZ-500RL7